19/94/125

# UNITED STATES PATENT AND TRADEMARK OFFICE CERTIFICATE OF CORRECTION

PATENT NO.

: 6.830.838 B2

DATED

: December 14, 2004

INVENTOR(S): Sandhu et al.

Page 1 of 2

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

# Title page,

Item [56], References Cited, OTHER PUBLICATIONS,

"Bachman, P., et al.," reference, delete "Bachman" and insert -- Bachmann --, therefor.

"Bouteville, A., et al.," reference, delete "TiSi2" and insert -- TiSi2 --, therefor; and delete "depositoin" and insert -- deposition --, therefor.

"Cowher, M., et al.," reference, delete (1997)" and insert -- (1979) --, therefor.

"Engqvist, J., et al.," reference, delete "TiSi2" and insert -- TiSi2 --, therefor; delete "H2-TiCl4" and insert -- H2\_TiCl4 --, therefor; and after 'and", delete "si:" and insert -- Si: --, therefor.

"Lee, J., et al.," reference, delete "TiSi2" and insert -- TiSi2 --, therefor.

"Moeller, T., et al.," reference, delete "Semiconductor" and insert

-- Semiconducting --, therefor.

"Rosler, R., et al.," reference, delete "198" and insert -- 1988 --, therefor.

### Column 1,

Line 29, delete "suicides" and insert -- suicides --, therefor.

## Column 7,

Line 29. delete "(I)" and insert -- (IV) --, therefor.

#### Column 8,

Line 27, after "via" insert --, --.

#### Column 9,

Line 29, after "wherein" insert -- the --.

Line 32, delete "(SiO2)" and insert -- (SiO2) --, therefor.

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Column 10,

Line 13, delete "(SiO2)" and insert -- (SiO<sub>2</sub>) --, therefor.

Signed and Sealed this

Tenth Day of May, 2005

JON W. DUDAS Director of the United States Patent and Trademark Office